# imall

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TOSHIBA Field Effect Transistor Silicon N Channel MOS Type

# RFM04U6P

#### VHF- and UHF-band Amplifier Applications

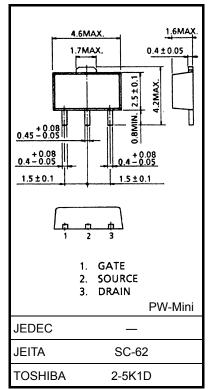
Unit: mm

(Note)The TOSHIBA products listed in this document are intended for high frequency Power Amplifier of telecommunications equipment.These TOSHIBA products are neither intended nor warranted for any other use.Do not use these TOSHIBA products listed in this document except for high frequency Power Amplifier of telecommunications equipment.

- Output power: PO = 4.3W (typ)
- Gain: Gp = 13.3dB (typ)
- Drain efficiency:  $\eta D = 70\%$  (typ)

#### Absolute Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Drain-source voltage	V <sub>DSS</sub>	16	V
Gain-source voltage	V <sub>GSS</sub>	3	V
Drain current	I <sub>D</sub>	2	А
Power dissipation	P <sub>D</sub> (Note 1)	7	W
Channel temperature	T <sub>ch</sub>	150	°C
Storage temperature range	T <sub>stg</sub>	-45 to 150	°C



Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in

temperature, etc.) may cause this product to decrease in the

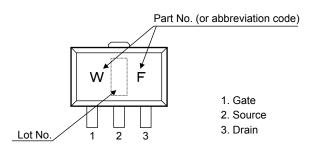
Weight: 0.05 g (typ.)

reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Tc = 25°C (When mounted on a 0.4 mm glass epoxy PCB with heat sink)

#### Marking



Caution: This device is sensitive to electrostatic discharge.

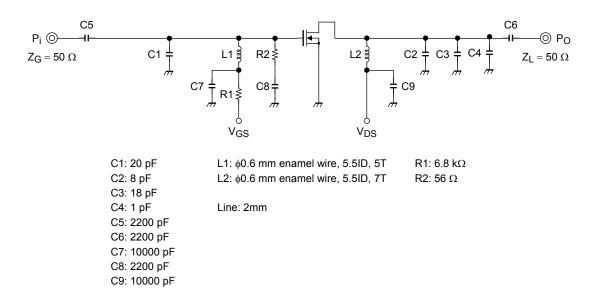
Please make enough tool and equipment earthed when you handle.

**Electrical Characteristics (Ta = 25°C)** 

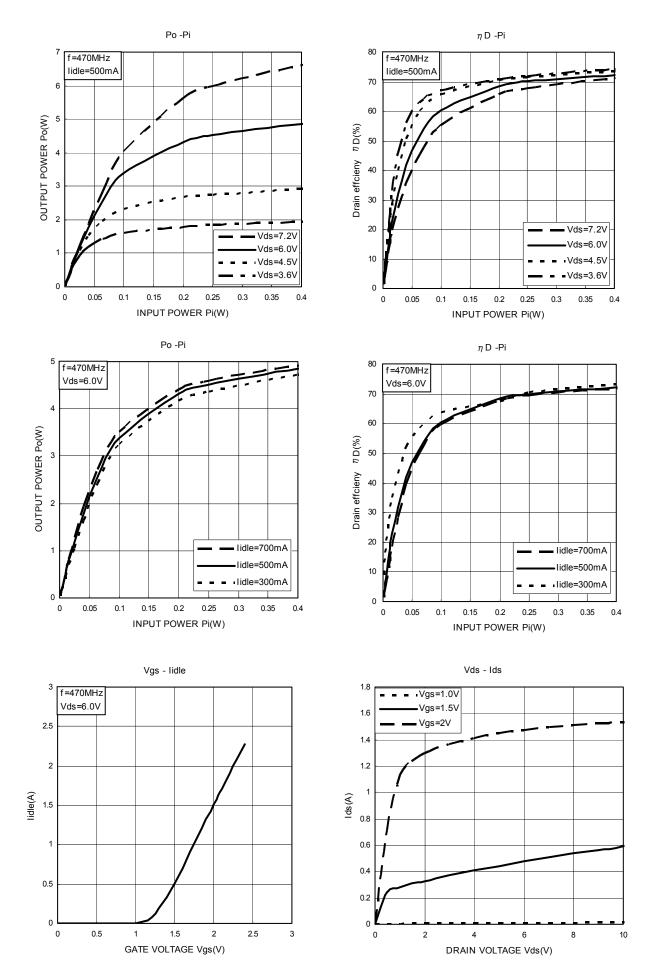
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Drain cut-off current	I <sub>DSS</sub>	$V_{DS} = 10 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$	_	_	10	μA
Gate-source leakage current	I <sub>GSS</sub>	V <sub>GS</sub> = 3 V			5	μA
Threshold voltage	V <sub>th</sub>	$V_{DS} = 6.0 \text{ V}, \text{ I}_{D} = 0.5 \text{mA}$	0.2	0.7	1.2	V
Output power	PO	V <sub>DS</sub> = 6.0 V, l <sub>idle</sub> = 500 mA (V <sub>GS</sub> = adjust), f = 470 MHz, P <sub>i</sub> = 200 mW, Z <sub>G</sub> = Z <sub>L</sub> = 50 Ω	3.5	4.3	_	W
Drain efficiency	η <sub>D</sub>		55	70		%
Power gain	GP		12.4	13.3	_	dB
Load mismatch	_	$\label{eq:VDS} \begin{array}{l} V_{DS} = 6.0 \text{ V}, \\ P_O = 4 \text{ W}(P_i = \text{adjust}), \\ I_{idle} = 500 \text{ mA } (V_{GS} = \text{adjust}), \\ f = 470 \text{ MHz}, \\ \text{VSWR LOAD } 20:1 \text{ all phase} \end{array}$	No degradation			

Note 2: These characteristic values are measured using measurement tools specified by Toshiba.

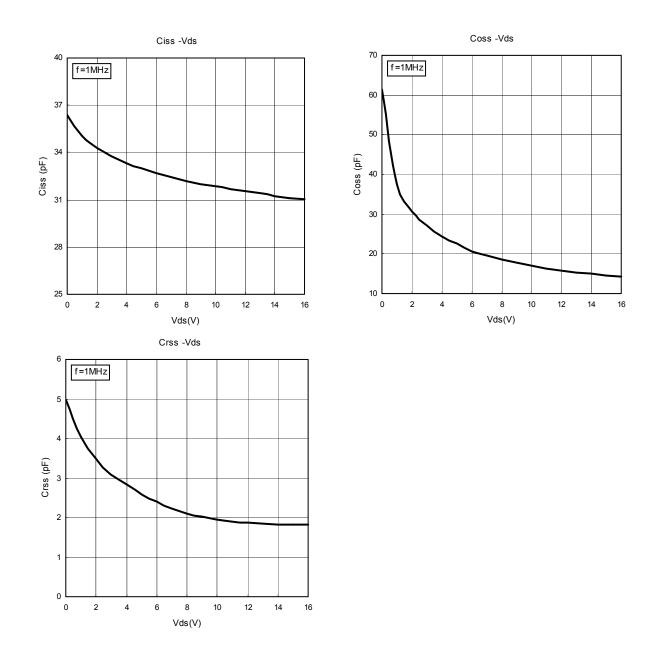
## Output Power Test Fixture (Test Condition: f = 470 MHz, $V_{DS} = 6.0$ V, $I_{idle} = 500$ mA, $P_i = 0.2$ W)



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Note 3: These are only typical curves and devices are not necessarily guaranteed at these curves.

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